MCH3484

Power MOSFET 20V, 40mΩ, 4.5A, Single N-Channel



www.onsemi.com

Features

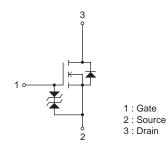
- On-Resistance RDS(on)1=33m Ω (typ)
- 0.9V Drive
- Pb-Free, Halogen Free and RoHS Compliance
- ESD Diode-Protected Gate

Specifications

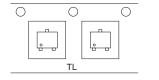
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	20	V
Gate to Source Voltage	VGSS	±5	V
Drain Current (DC)	ID	4.5	Α
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	I _{DP}	18	А
Power Dissipation When mounted on ceramic substrate (900mm²×0.8mm)	PD	1.0	W
Junction Temperature	Tj	150	°C
Operating Temperature	Topr	−5 to +150	°C
Storage Temperature	Tstg	–55 to +150	°C

Electrical Connection N-Channel



Packing Type: TL Marking





Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm² × 0.8mm)	$R_{ heta JA}$	125	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

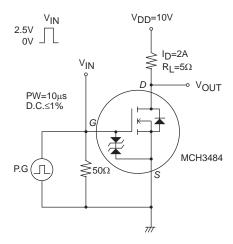
MCH3484

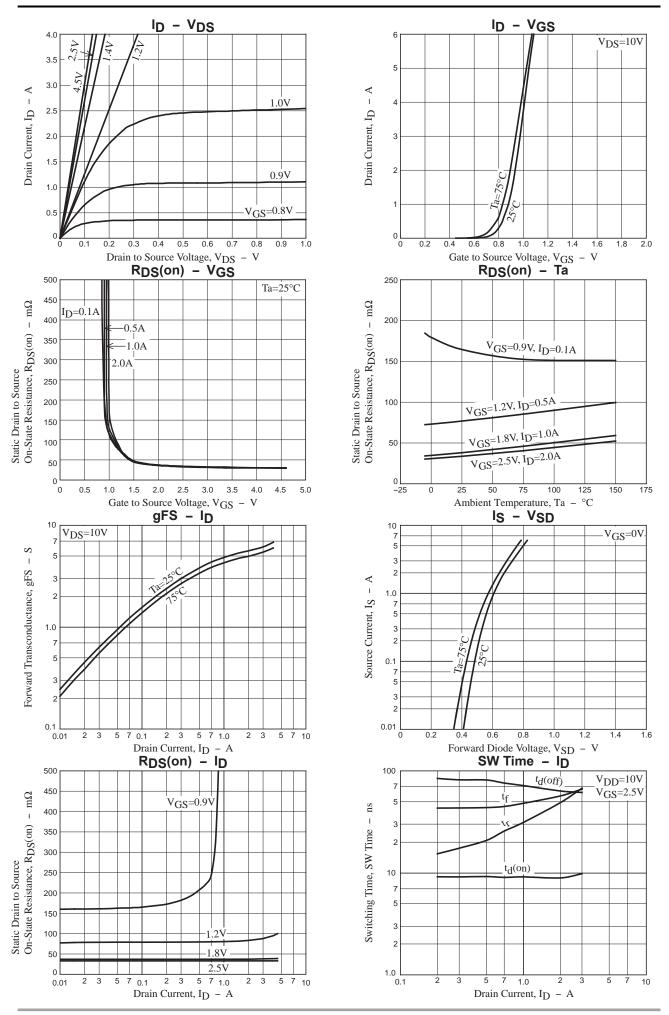
Electrical Characteristics at Ta = 25°C

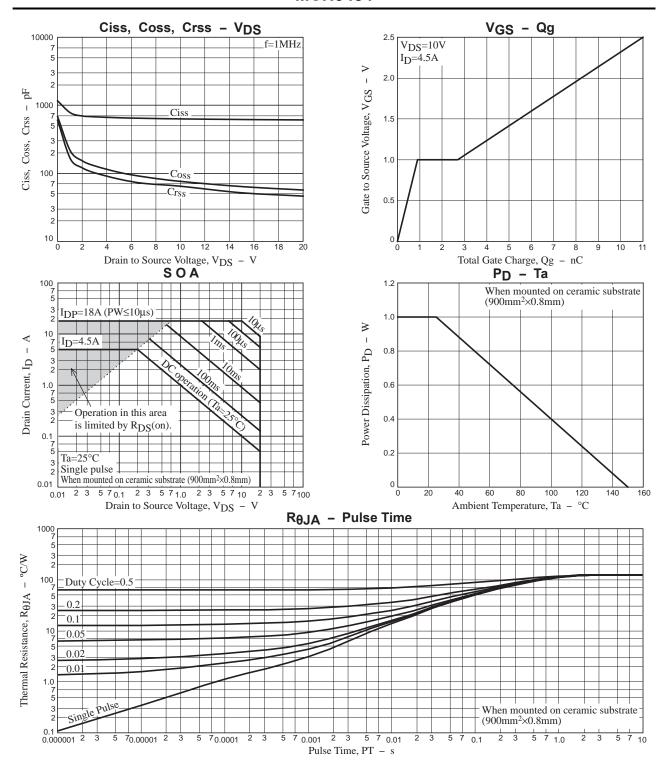
Danier etc.	0	Symbol Conditions		Value		
Parameter	Symbol		min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μА
Gate to Source Leakage Current	IGSS	V _{GS} =±4V, V _{DS} =0V			±10	μА
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =10V, I _D =1mA	0.3		0.8	V
Forward Transconductance	9FS	V _{DS} =10V, I _D =2A		5.6		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =2A, V _{GS} =2.5V		33	40	mΩ
	R _{DS} (on)2	I _D =1A, V _{GS} =1.8V		37	49	mΩ
	R _{DS} (on)3	I _D =0.5A, V _{GS} =1.2V		79	119	mΩ
	R _{DS} (on)4	I _D =0.1A, V _{GS} =0.9V		165	330	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		630		pF
Output Capacitance	Coss			75		pF
Reverse Transfer Capacitance	Crss	1		65		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		8.9		ns
Rise Time	t _r			49		ns
Turn-OFF Delay Time	t _d (off)			63		ns
Fall Time	tf	7		57		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =2.5V, I _D =4.5A		11		nC
Gate to Source Charge	Qgs			0.9		nC
Gate to Drain "Miller" Charge	Qgd	1		1.8		nC
Forward Diode Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V		0.8	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit







Package Dimensions

MCH3484-TL-H / MCH3484-TL-W

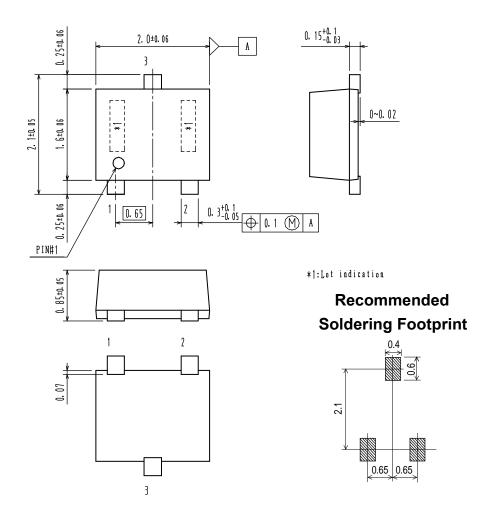
MCPH3

CASE 419AQ ISSUE O

unit: mm

1 : Gate 2 : Source

3: Drain



ORDERING INFORMATION

Device	Package	Shipping	Note	
MCH3484-TL-H	MCPH3	3,000 pcs. / reel	Pb-Free	
MCH3484-TL-W	484-TL-W SC-70,SOT-323		and Halogen Free	

Note on usage: Since the MCH3484 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent reg